LM1117-Q1 18V, 1A, Automotive, Fixed-Output Linear Voltage Regulator

1 Features

- AEC-Q100 qualified for automotive applications:
  - Temperature grade 1: –40°C to +125°C, T_A
  - Junction temperature: –40°C to +150°C, T_J
- Input voltage range V_{IN}:
  - Absolute maximum: 20V
  - Operating range: 2.5V to 18V
- Output voltage range V_{OUT}:
  - 1.2V, 3.3V, 5V, 12V fixed
  - 0.8V to 13.0V (fixed, 100mV steps) available upon request
- Output current: Up to 1A
- Low quiescent current I_Q: 65µA (typical)
- ±1% output accuracy
- High PSRR:
  - 60dB at 1kHz
  - 40dB at 1MHz
- Internal soft-start time: 500µs (typical)
- Foldback current limiting and thermal protection
- Stable with 1µF ceramic output capacitors
- Packages:
  - SOT-223 (DCY), $R_{\theta JA}$= 95.4°C/W
  - TO-252 (KVU), $R_{\theta JA}$= 67.2°C/W

2 Applications

- Onboard chargers
- Traction inverters
- 2-wheeler and 3-wheeler traction drives
- DC/DC converter systems

3 Description

The LM1117-Q1 is an AEC-Q100 qualified linear voltage regulator for automotive applications. The device provides improved performance compared to traditional x1117 regulators, with tighter output accuracy and low quiescent current (I_Q) to minimize standby power consumption.

The LM1117-Q1 input voltage range is from 2.5V to 18V (20V absolute maximum). The device is available in 1.2V, 3.3V, 5V, and 12V fixed output voltages.
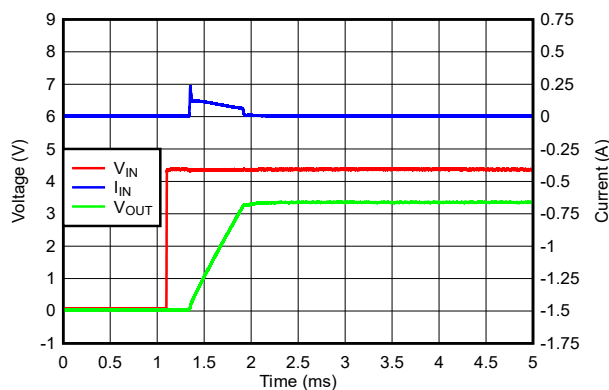
The wide bandwidth PSRR performance of the LM1117-Q1 is typically greater than 60dB at 1kHz and 40dB at 1MHz, which attenuates the switching frequency of an upstream DC/DC converter.

Additionally, the LM1117-Q1 has an internal soft-start feature to reduce inrush current during start-up, which helps save space and cost in a design by minimizing the need for input capacitance. The LM1117-Q1 features a foldback current limit that reduces the power dissipation of the device during high-load current faults or shorting events.
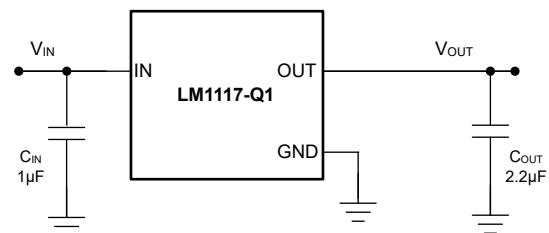
Package Information

PART NUMBER	PACKAGE[1]	PACKAGE SIZE[2]
LM1117-Q1	DCY (SOT-223, 4)	6.5mm × 7mm
	KVU (TO-252, 3)	6.6mm × 10.11mm

(1) For more information, see the *Mechanical, Packaging, and Orderable Information*.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.

Start-Up and Inrush Current With 22µF at C_{OUT}

Typical Application Circuit

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Product Folder Links: *LM1117-Q1*

4 Pin Configuration and Functions

Figure 4-1. DCY Package, 4-Pin SOT-223 (Top View)
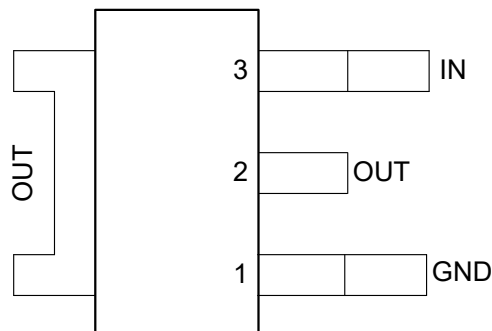
Figure 4-2. KVU Package, 3-Pin TO-252 (Top View)

Table 4-1. Pin Functions

PIN				DESCRIPTION
NAME	DCY	KVU	FUNCTION	
GND	1	1	—	Ground pin
OUT	2, Tab	2, Tab	O	Output pin. Use the recommended capacitor value as listed in the *Recommended Operating Conditions* table. Place the output capacitor as close to the OUT and GND pins of the device as possible.
IN	3	3	I	Input pin. Use the recommended capacitor value as listed in the *Recommended Operating Conditions* table. Place the input capacitor as close to the IN and GND pins of the device as possible.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

		MIN	MAX	UNIT
Voltage [2]	V_{IN}	−0.3	20	V
	V_{OUT} [3]	−0.3	V_{IN} + 0.3	
Current	Maximum output current	Internally limited		A
Power	Power dissipation	Package limited [4]		W
Temperature	Operating junction (T_j)	−50	150	°C
	Storage (T_{stg})	−65	150	

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) All voltages with respect to GND.
(3) V_{IN} + 0.3V or 20V (whichever is smaller).
(4) See Thermal Information table for further details.

5.2 ESD Ratings

				VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per AEC Q100-002, all pins[1]		±3000	V
		Charged device model (CDM), per AEC Q100-011	Corner pins (1 and 3)	±1000	
			Other pins	±1000	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{IN}	Input voltage	2.5		18	V
V_{OUT}	Output voltage	0.8		13.0	
I_{OUT}	Output current (2.5V ≤ V_{IN} < 3V)	0		0.8	A
I_{OUT}	Output current (V_{IN} ≥ 3V)	0		1	
C_{OUT} ESR	Output capacitor ESR	2		500	mΩ
C_{OUT}	Output capacitor[1]	1	2.2	220	μF
C_{IN}	Input capacitor[2]		1		
T_J	Junction temperature	−40		150	°C

(1) Effective output capacitance of 0.47μF minimum required for stability.
(2) An input capacitor is not required for LDO stability. However, an input capacitor with an effective value of 0.47μF minimum is recommended to counteract the effect of source resistance and inductance, which may in some cases cause symptoms of system level instability such as ringing or oscillation, especially in the presence of load transients.

5.4 Thermal Information

THERMAL METRIC[1]		LM1117-Q1		UNIT
		DCY (SOT–223)	KVU (TO–252)	
		4 PINS	4 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	95.4	67.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	55.6	71.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	33.7	45.5	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	13.9	31.6	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	33.4	45.4	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	40.5	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application note.

5.5 Electrical Characteristics

specified at T_J = –40°C to 150°C, V_{IN} = $V_{OUT(nom)}$ + 1.5V or V_{IN} = 2.5V (whichever is greater), I_{OUT} = 10mA, C_{IN} = 1.0µF and C_{OUT} = 1.0µF (unless otherwise noted); typical values are at T_J= 25°C.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OUT}	Nominal output accuracy	T_J = 25°C	−1		1	%
V_{OUT}	Output accuracy over temperature	VIN ≥ 3.0V, $V_{OUT(NOM)}$ ≤ 9.0V, 1mA ≤ I_{OUT} ≤ 1A	−1.75		1.75	%
		$V_{OUT(NOM)}$ > 9.0V, 1mA ≤ I_{OUT} ≤ 1A	−1.75		1.75	
$\Delta V_{OUT(\Delta VIN)}$	Line regulation[1]	$V_{OUT(NOM)}$ ≤ 9.0V, $V_{OUT(NOM)}$ + 1.5V ≤ V_{IN} ≤ 18V, I_{OUT} = 10mA			0.02	%/V
		$V_{OUT(NOM)}$ > 9.0V, $V_{OUT(NOM)}$ + 1.5V ≤ V_{IN} ≤ 18V, I_{OUT} = 10mA			13.5	mV
$\Delta V_{OUT(\Delta IOUT)}$	Load regulation	1mA ≤ I_{OUT} ≤ 1A, V_{IN} ≥ 3.0V		0.1	0.75	%/A
V_{DO}	Dropout voltage[2]	V_{IN} ≥ 3.0V, I_{OUT} = 1A		0.9	1.7	V
I_{CL}	Output current limit	V_{OUT} = 0.9 x $V_{OUT(NOM)}$, V_{IN} = $V_{OUT(nom)}$ + 1.5V or V_{IN} = 4.3V (whichever is greater)	1.1		1.6	A
I_{SC}	Short-circuit current limit	V_{OUT} = 0V	150	250	350	mA
I_Q	Quiescent current	I_{OUT} = 0mA		65	110	µA
$I_{PULLDOWN}$	Output pulldown current[3]	V_{IN} = 1.8V, V_{OUT} = 2.5V	0.7		1.1	mA
PSRR	Power-supply rejection ratio	V_{IN} = 3.3V, V_{OUT} = 1.8V, I_{OUT} = 300mA, f = 120Hz		70		dB
V_n	Output noise voltage	BW = 10Hz to 100kHz, V_{IN} = 3.3V, V_{OUT} = 0.8V, I_{OUT} = 100mA		60		µV$_{RMS}$
V_{UVLO+}	UVLO threshold rising	V_{IN} rising		2.2	2.4	V
$V_{UVLO(HYS)}$	UVLO hysteresis			130		mV
V_{UVLO-}	UVLO threshold falling	V_{IN} falling	1.9			V
$T_{SD(shutdown)}$	Thermal shutdown temperature	Temperature increasing		180		°C
$T_{SD(reset)}$	Thermal shutdown reset temperature	Temperature falling		160		°C

(1) Line regulation is measured with V_{IN} = $V_{OUT(NOM)}$ + 1.5V or 2.5V (whichever is greater).
(2) V_{DO} is measured with V_{IN} = 95% x $V_{OUT(nom)}$ for fixed output devices. V_{DO} is not measured for fixed output devices when V_{OUT} < 2.5V.
(3) $I_{PULLDOWN}$ is measured with V_{IN} = 1.8V (lower than UVLO falling threshold, with LDO in disabled state) and 2.5V applied on V_{OUT} externally.

5.6 Typical Characteristics

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 1.5V or 2.5V (whichever is greater), I_{OUT} = 10mA, C_{IN} = 1.0µF, and C_{OUT} = 1.0µF (unless otherwise noted)

V_{IN} ≥ 3.0V
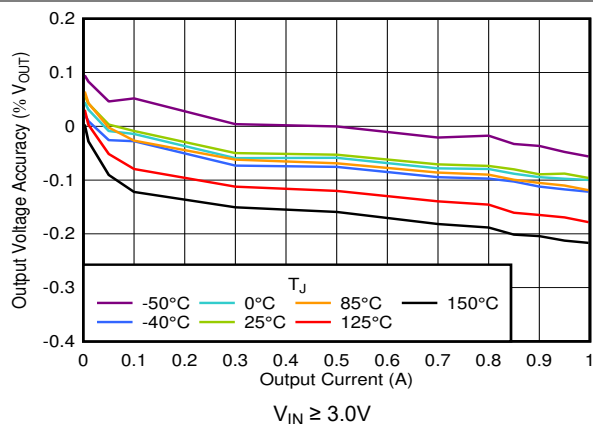
Figure 5-1. V_{OUT} Accuracy vs I_{OUT}

I_{OUT} = 10mA
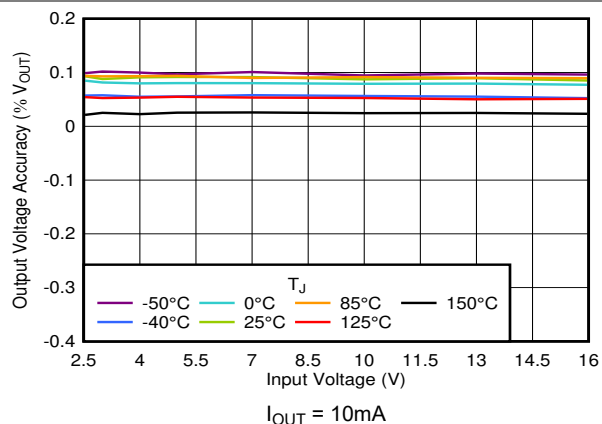
Figure 5-2. V_{OUT} Accuracy vs V_{IN}

I_{OUT} = 0mA
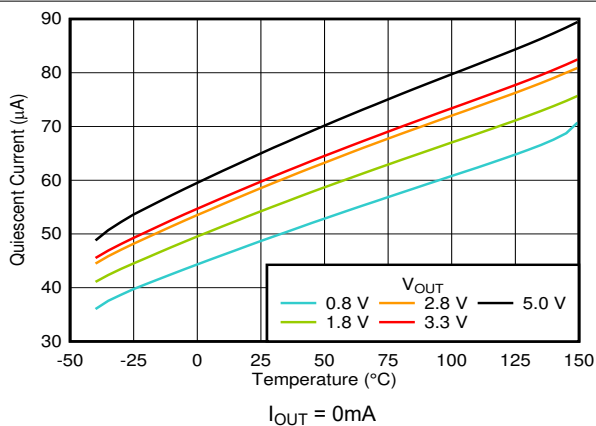
Figure 5-3. I_Q vs Temperature

I_{OUT} = 0mA
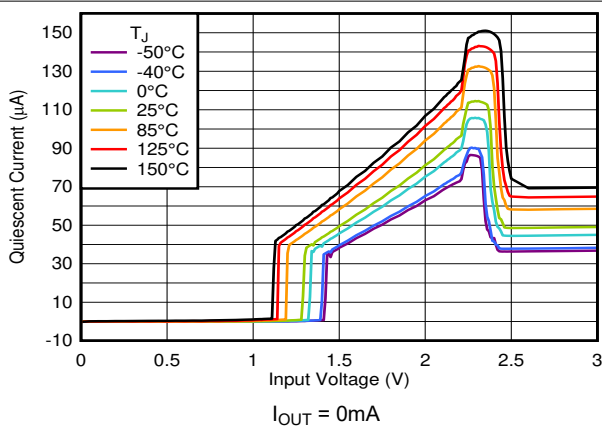
Figure 5-4. I_Q Increase Below Minimum V_{IN}

V_{IN} ≥ 3.0V

Figure 5-5. I_{GND} vs I_{OUT}

V_{IN} = 5V, V_{OUT} = 3.3V, ramp rate = 0.4A/µs
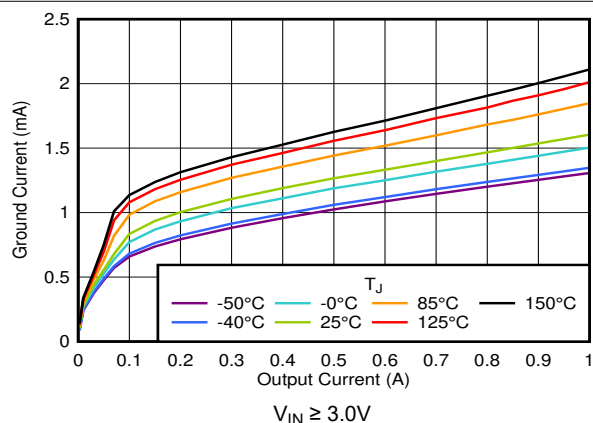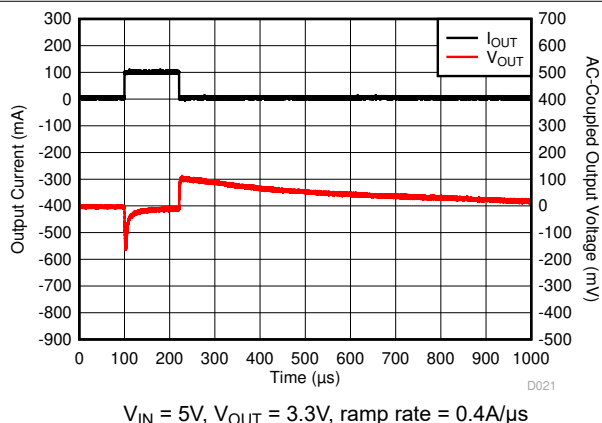
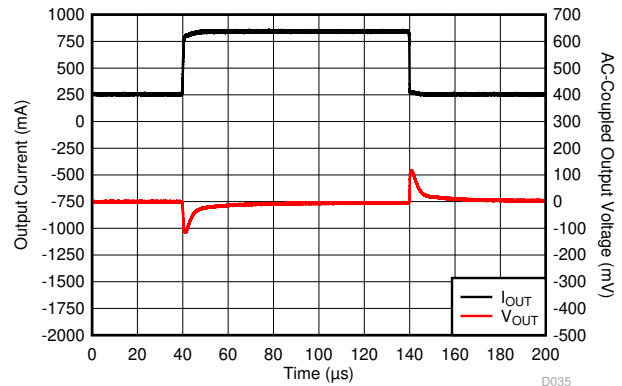**Figure 5-6. I_{OUT} Transient From 0mA to 100mA**

Product Folder Links: *LM1117-Q1*

5.6 Typical Characteristics (continued)

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 1.5V or 2.5V (whichever is greater), I_{OUT} = 10mA, C_{IN} = 1.0µF, and C_{OUT} = 1.0µF (unless otherwise noted)
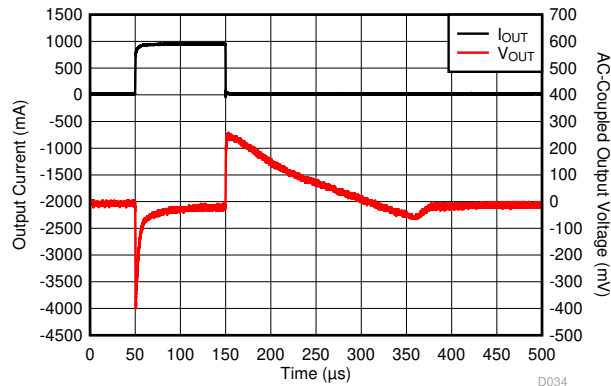
V_{IN} = 5V, V_{OUT} = 3.3V, ramp rate = 0.5A/µs

Figure 5-7. I_{OUT} Transient From 1mA to 1A

V_{IN} = 5V, V_{OUT} = 3.3V, ramp rate = 0.8A/µs

Figure 5-8. I_{OUT} Transient From 250mA to 850mA
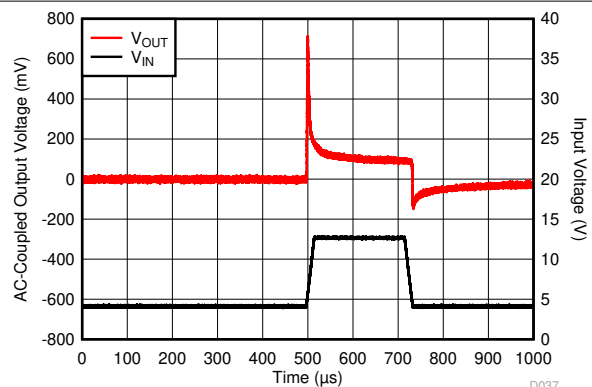
V_{IN} = 5V, V_{OUT} = 3.3V, I_{OUT} = 1A, V_{IN} ramp rate = 0.6V/µs

Figure 5-9. V_{IN} Transient in Dropout From 4V to 13V
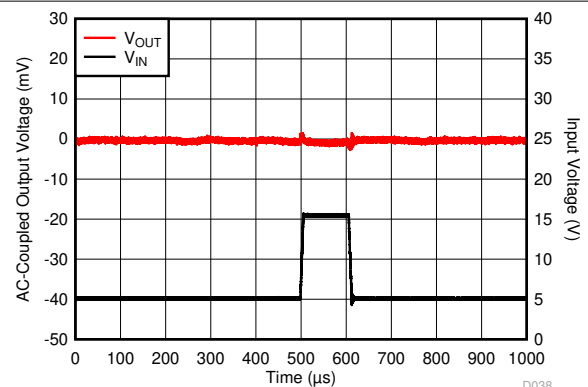
V_{OUT} = 3.3V, I_{OUT} = 33µA, V_{IN} ramp rate = 1.6V/µs

Figure 5-10. V_{IN} Transient From 5V to 16V
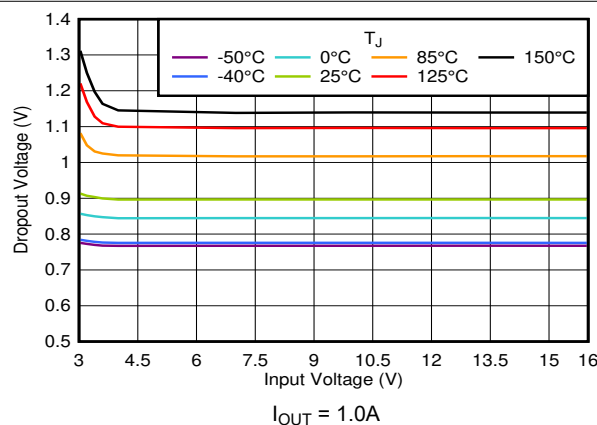
I_{OUT} = 1.0A

Figure 5-11. V_{DO} vs V_{IN}
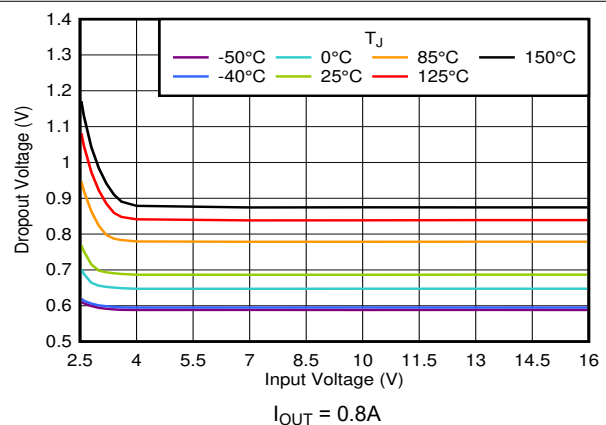
I_{OUT} = 0.8A

Figure 5-12. V_{DO} vs V_{IN}

5.6 Typical Characteristics (continued)

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 1.5V or 2.5V (whichever is greater), I_{OUT} = 10mA, C_{IN} = 1.0µF, and C_{OUT} = 1.0µF (unless otherwise noted)
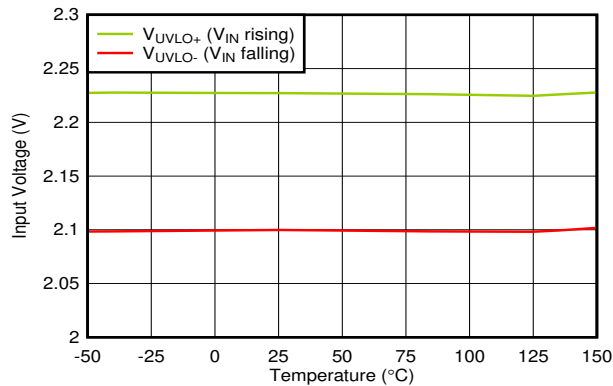
Figure 5-13. UVLO Thresholds vs Temperature

$V_{IN} \geq 3.0V$
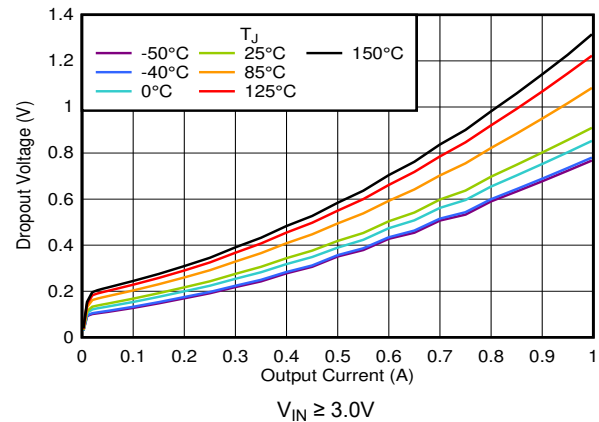
Figure 5-14. V_{DO} vs I_{OUT}

$V_{IN} \geq 3.0V$
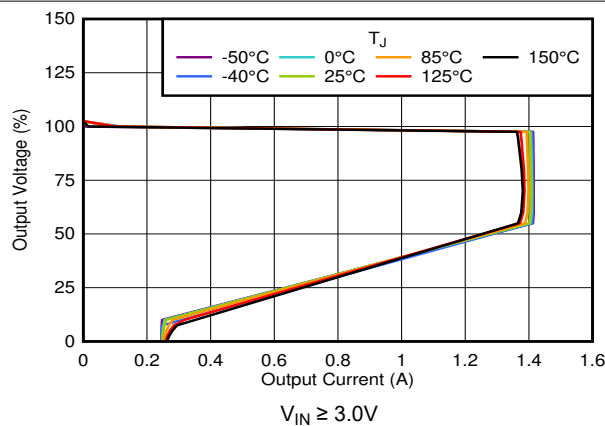
Figure 5-15. Foldback Current Limit vs Temperature
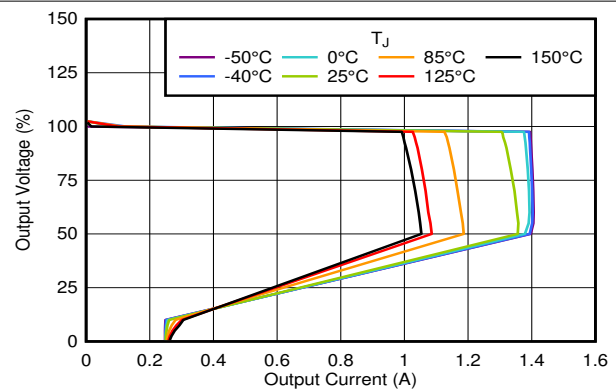
Figure 5-16. Foldback Current Limit vs Temperature

V_{OUT} = 1.8V, V_{IN} = 3.3V
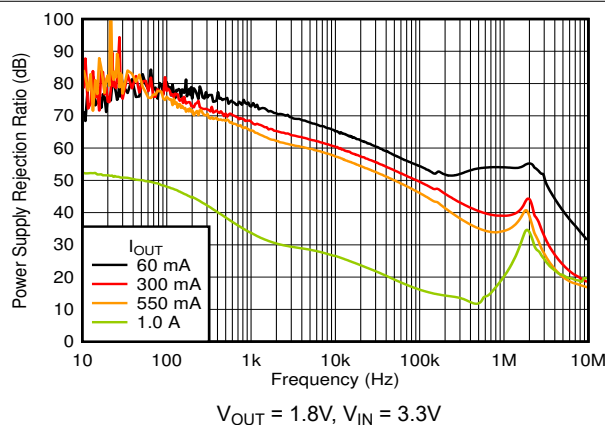
Figure 5-17. PSRR vs I_{OUT}
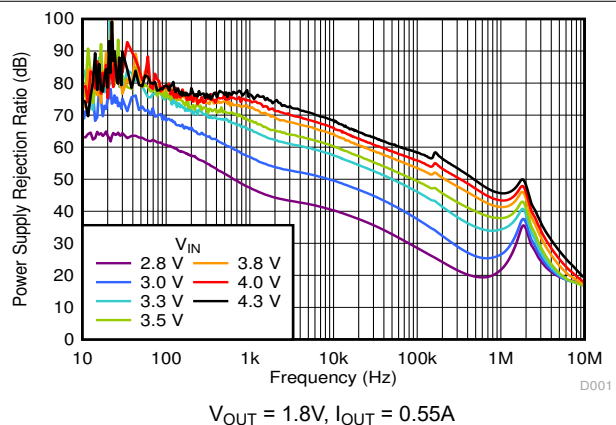
V_{OUT} = 1.8V, I_{OUT} = 0.55A

Figure 5-18. PSRR vs V_{IN}

Product Folder Links: *LM1117-Q1*

5.6 Typical Characteristics (continued)

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 1.5V or 2.5V (whichever is greater), I_{OUT} = 10mA, C_{IN} = 1.0µF, and C_{OUT} = 1.0µF (unless otherwise noted)
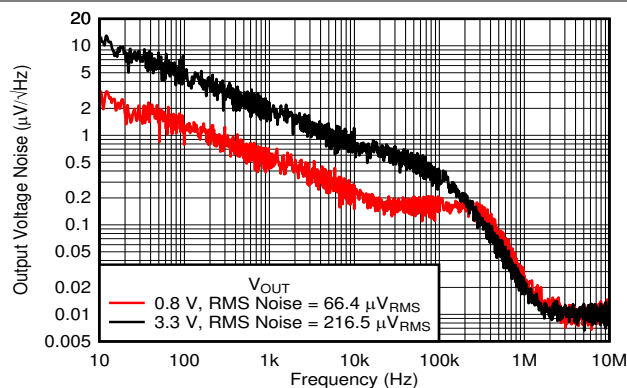
I_{OUT} = 0.1A, RMS noise BW = 10Hz to 100kHz

Figure 5-19. Output Noise (V_n) vs V_{OUT}
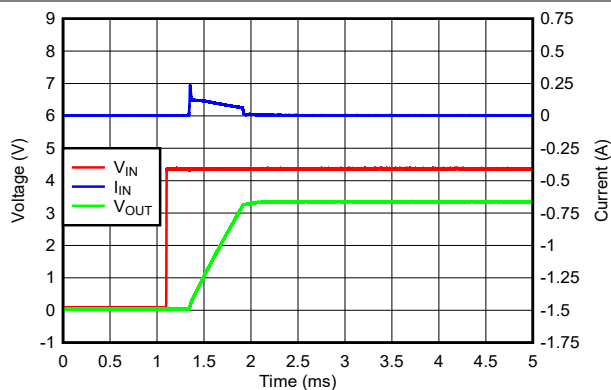
I_{OUT} = 0.1A, C_{OUT} = 22µF

Figure 5-20. Inrush Current With 22µF at C_{OUT}

Product Folder Links: *LM1117-Q1*

6 Detailed Description

6.1 Overview

The LM1117-Q1 is a AEC-Q100 qualified, low quiescent current, high PSRR linear regulator capable of sourcing load current up to 1A. This device is designed for high current automotive applications in HEV/EV and power train systems where there are increasingly stringent requirements for standby and active power consumption.

This device features integrated foldback current limit, thermal shutdown, internal output pulldown, and undervoltage lockout (UVLO). This device delivers excellent line and load transient performance. The LM1117-Q1 is low noise and exhibits very good PSRR. The operating ambient temperature range of the device is –40°C to +125°C.

6.2 Functional Block Diagram

6.3 Feature Description

6.3.1 Dropout Voltage

Dropout voltage (V_{DO}) is defined as the input voltage minus the output voltage ($V_{IN} - V_{OUT}$) at the rated output current (I_{RATED}), where the pass transistor is fully turned on. I_{RATED} is the maximum I_{OUT} listed in the *Recommended Operating Conditions* table. The pass transistor is in the ohmic or triode region of operation, and acts as a switch. The dropout volta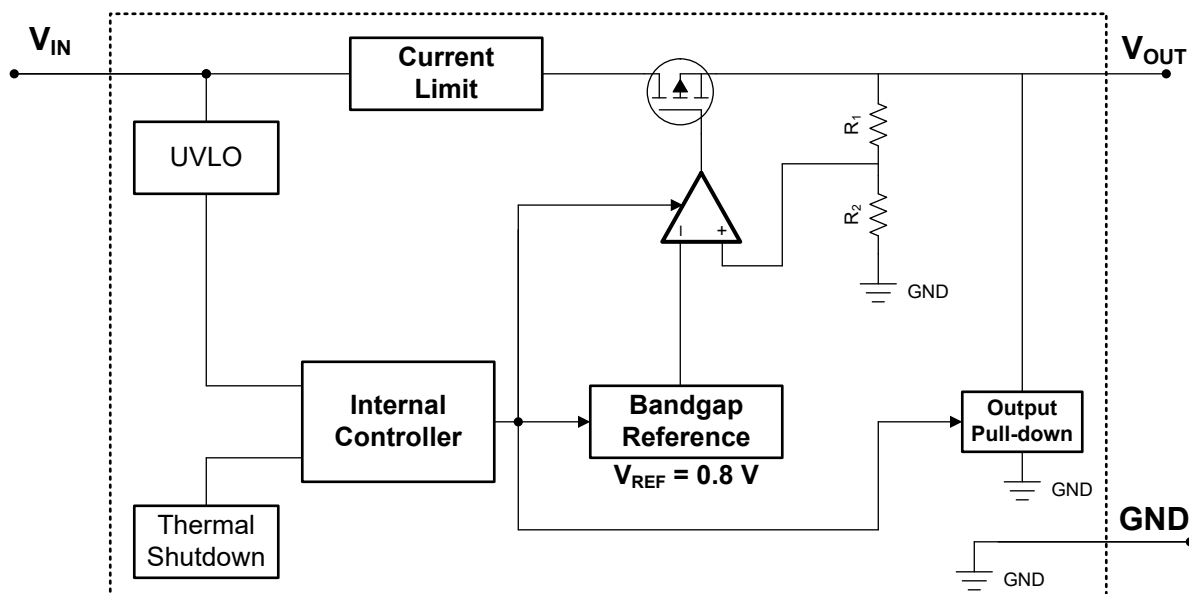ge indirectly specifies a minimum input voltage greater than the nominal programmed output voltage at which the output voltage is expected to stay in regulation. If the input voltage falls to less than the nominal output regulation, then the output voltage falls as well.

For a CMOS regulator, the dropout voltage is determined by the drain-source on-state resistance ($R_{DS(ON)}$) of the pass transistor. Therefore, if the linear regulator operates at less than the rated current, the dropout voltage for that current scales accordingly. Use the following equation to calculate the $R_{DS(ON)}$ of the device.

$$R_{DS(ON)} = \frac{V_{DO}}{I_{RATED}}$$

(1)

Product Folder Links: *LM1117-Q1*

6.3.2 Foldback Current Limit

The device has an internal current limit circuit that protects the regulator during transient high-load current faults or shorting events. The current limit is a hybrid brick-wall-foldback scheme. The current limit transitions from a brick-wall scheme to a foldback scheme at the foldback voltage ($V_{FOLDBACK}$). In a high-load current fault with the output voltage above $V_{FOLDBACK}$, the brick-wall scheme limits the output current to the current limit (I_{CL}). When the voltage drops below $V_{FOLDBACK}$, a foldback current limit activates that scales back the current as the output voltage approaches GND. When the output is shorted, the device supplies a typical current called the short-circuit current limit (I_{SC}). I_{CL} and I_{SC} are listed in the *Electrical Characteristics* table.

For this device, $V_{FOLDBACK} = 50\% \times V_{OUT(nom)}$.

The output voltage is not regulated when the device is in current limit. When a current limit event occurs, the device begins to heat up because of the increase in power dissipation. When the device is in brick-wall current limit, the pass transistor dissipates power [$(V_{IN} - V_{OUT}) \times I_{CL}$]. When the device output is shorted and the output is below $V_{FOLDBACK}$, the pass transistor dissipates power [$(V_{IN} - V_{OUT}) \times I_{SC}$]. If thermal shutdown is triggered, the device turns off. After the device cools down, the internal thermal shutdown circuit turns the device back on. If the output current fault condition continues, the device cycles between current limit and thermal shutdown. For more information on current limits, see the *Know Your Limits* application note.

Figure 6-1 shows a diagram of the foldback current limit.
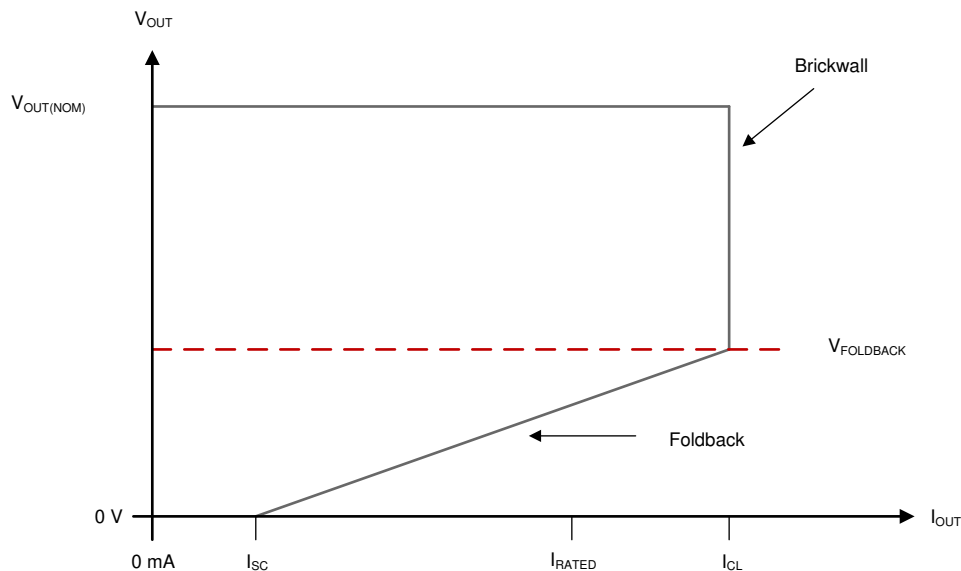
Figure 6-1. Foldback Current Limit

6.3.3 Undervoltage Lockout (UVLO)

The device has an independent undervoltage lockout (UVLO) circuit that monitors the input voltage, allowing a controlled and consistent turn-on and turn-off of the output voltage. To prevent the device from turning off if the input drops during turn-on, the UVLO has hysteresis as specified in the *Electrical Characteristics* table.

6.3.4 Output Pulldown

The device has an output pulldown circuit. V_{OUT} pulldown sink to ground capability is listed in the *Electrical Characteristics* table. The output pulldown activates under the following conditions:

- Device disabled
- $1.0V < V_{IN} < V_{UVLO}$

The output pulldown current for this device is 0.9mA typical.

Do not rely on the output pulldown circuit for discharging a large amount of output capacitance after the input supply collapses. When the input supply collapses, reverse current flows from the output to the input, and this reverse current causes damage to the device. See the *Reverse Current* section for more details.

6.3.5 Thermal Shutdown

The device contains a thermal shutdown protection circuit to disable the device when the junction temperature (T_J) of the pass transistor rises to $T_{SD(shutdown)}$ (typical). Thermal shutdown hysteresis makes sure the device resets (turns on) when the temperature falls to $T_{SD(reset)}$ (typical).

The thermal time-constant of the semiconductor die is fairly short. Thus the device cycles on and off when thermal shutdown is reached until power dissipation is reduced. Power dissipation during start-up is high from large $V_{IN} - V_{OUT}$ voltage drops across the device or from high inrush currents charging large output capacitors. Under some conditions, the thermal shutdown protection disables the device before start-up completes.

For reliable operation, limit the junction temperature to the maximum listed in the *Recommended Operating Conditions* table. Operation above this maximum temperature causes the device to exceed operational specifications. Although the device internal protection circuitry is designed to protect against thermal overall conditions, this circuitry is not intended to replace proper heat sinking. Continuously running the device into thermal shutdown or above the maximum recommended junction temperature reduces long-term reliability.

Product Folder Links: *LM1117-Q1*

6.4 Device Functional Modes

Table 6-1 shows the conditions that lead to the different modes of operation. See the *Electrical Characteristics* table for parameter values.

Table 6-1. Device Functional Mode Comparison

OPERATING MODE	PARAMETER		
	V_{IN}	I_{OUT}	T_J
Normal operation	$V_{IN} > V_{OUT(nom)} + V_{DO}$ and $V_{IN} > V_{IN(min)}$	$I_{OUT} < I_{OUT(max)}$	$T_J < T_{SD(shutdown)}$
Dropout operation	$V_{IN(min)} < V_{IN} < V_{OUT(nom)} + V_{DO}$	$I_{OUT} < I_{OUT(max)}$	$T_J < T_{SD(shutdown)}$
Disabled (any true condition disables the device)	$V_{IN} < V_{UVLO}$	Not applicable	$T_J > T_{SD(shutdown)}$

6.4.1 Normal Operation

The device regulates to the nominal output voltage when the following conditions are met:

- The input voltage is greater than the nominal output voltage plus the dropout voltage ($V_{OUT(nom)} + V_{DO}$)
- The output current is less than the current limit ($I_{OUT} < I_{CL}$)
- The device junction temperature is less than the thermal shutdown temperature ($T_J < T_{SD}$)

6.4.2 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this mode, the output voltage tracks the input voltage. During this mode, the transient performance of the device becomes significantly degraded because the pass transistor is in the ohmic or triode region, and acts as a switch. Line or load transients in dropout result in large output-voltage deviations.

When the device is in a steady dropout state (defined as when the device is in dropout, $V_{IN} < V_{OUT(NOM)} + V_{DO}$, directly after being in a normal regulation state, but *not* during start-up), the pass transistor is driven into the ohmic or triode region. When the input voltage returns to a value greater than or equal to the nominal output voltage plus the dropout voltage ($V_{OUT(NOM)} + V_{DO}$), the output voltage overshoots for a short period of time while the device pulls the pass transistor back into the linear region.

6.4.3 Disabled

The device output is disabled if V_{IN} is less than the UVLO voltage, or if the device junction temperature exceeds the thermal shutdown threshold. See the *Electrical Characteristics* table for more details regarding the UVLO voltage thresholds and thermal shutdown. When disabled, the pass transistor turns off and internal circuits shut down. The output voltage is also actively discharged to ground by an internal discharge circuit from the output to ground.

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

7.1.1 Recommended Capacitor Types

The device is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input and output. Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but use good judgment. Ceramic capacitors that employ X7R-, X5R-, and C0G-rated dielectric materials provide relatively good capacitive stability across temperature. Whereas using Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, the effective capacitance varies with operating voltage and temperature. Generally, expect the effective capacitance to decrease by as much as 50%. The input and output capacitors recommended in the *Recommended Operating Conditions* table account for an effective capacitance of approximately 50% of the nominal value.

7.1.2 Input and Output Capacitor Requirements

Although an input capacitor is not required for stability, good analog design practice is to connect a capacitor from IN to GND. This capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. An input capacitor is recommended if the source impedance is more than 0.5Ω. A higher value capacitor is necessary if large, fast rise-time load or line transients are anticipated or if the device is located several inches from the input power source.

Dynamic performance of the device is improved with the use of an output capacitor. Use an output capacitor within the range specified in the *Recommended Operating Conditions* table for stability.

7.1.3 Reverse Current

Excessive reverse current damages this device. Reverse current flows through the intrinsic body diode of the pass transistor instead of the normal conducting channel. At high magnitudes, this current flow degrades the long-term reliability of the device.

Conditions where reverse current occurs are outlined in this section, all of which exceed the absolute maximum rating of $V_{OUT} \leq V_{IN} + 0.3V$.

- If the device has a large C_{OUT} and the input supply collapses with little or no load current
- The output is biased when the input supply is not established
- The output is biased above the input supply

If reverse current flow is expected in the application, external protection is recommended to protect the device. Reverse current is not limited in the device, so external limiting is required if extended reverse voltage operation is anticipated.

Product Folder Links: *LM1117-Q1*

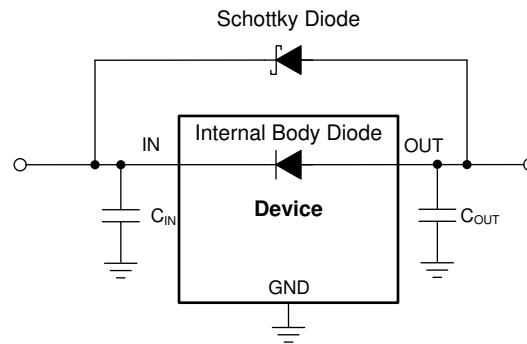Figure 7-1 shows one approach for protecting the device.

Figure 7-1. Example Circuit for Reverse Current Protection Using a Schottky Diode

7.1.4 Power Dissipation (P_D)

Circuit reliability requires consideration of the device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. Make sure the PCB area around the regulator has few or no other heat-generating devices that cause added thermal stress.

To first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. Use the following equation to calculate the power dissipation (P_D).

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \tag{2}$$

Note

Power dissipation is minimized, and therefore greater efficiency achieved, by correct selection of the system voltage rails. For the lowest power dissipation, use the minimum input voltage required for correct output regulation.

For devices with a thermal pad, the primary heat conduction path for the device package is through the thermal pad to the PCB. Solder the thermal pad to a copper pad area under the device. Make sure this pad area contains an array of plated vias that conduct heat to additional copper planes for increased heat dissipation.

The maximum power dissipation determines the maximum allowable ambient temperature (T_A) for the device. According to the following equation, power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ($R_{\theta JA}$) of the combined PCB and device package and the temperature of the ambient air (T_A).

$$T_J = T_A + (R_{\theta JA} \times P_D) \tag{3}$$

Thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The junction-to-ambient thermal resistance listed in the *Thermal Shutdown* table is determined by the JEDEC standard PCB and copper-spreading area, and is used as a relative measure of package thermal performance. This thermal resistance is used as a relative measure of package thermal performance. $R_{\theta JA}$ is improved by 35% to 55% compared to the *Thermal Shutdown* table value with the PCB board layout optimization. See the *An empirical analysis of the impact of board layout on LDO thermal performance* application note for further details

7.1.5 Estimating Junction Temperature

The JEDEC standard now recommends the use of psi (Ψ) thermal metrics to estimate the junction temperatures of the linear regulator when in-circuit on a typical printed circuit board application. These metrics are not thermal resistance parameters and instead offer a practical and relative way to estimate junction temperature. These psi metrics are determined to be significantly independent of the copper area available for heat-spreading. The *Thermal Shutdown* table lists the primary thermal metrics, which are the junction-to-top characterization parameter (ψ_{JT}) and junction-to-board characterization parameter (ψ_{JB}). These parameters provide two methods for calculating the junction temperature (T_J). As described in the following equations, use the junction-to-top characterization parameter (ψ_{JT}) with the temperature at the center-top of device package (T_T) to calculate the junction temperature. Use the junction-to-board characterization parameter (ψ_{JB}) with the PCB surface temperature 1mm from the device package (T_B) to calculate the junction temperature.

$$T_J = T_T + \psi_{JT} \times P_D \tag{4}$$

where:

- P_D is the dissipated power
- T_T is the temperature at the center-top of the device package

$$T_J = T_B + \psi_{JB} \times P_D \tag{5}$$

where:

- T_B is the PCB surface temperature measured 1mm from the device package and centered on the package edge

For detailed information on the thermal metrics and how to use them, see the *Semiconductor and IC Package Thermal Metrics* application note.

7.2 Typical Application

The LM1117-Q1 is an AEC-Q100 qualified, low quiescent current linear regulator designed for high-current automotive applications. Unlike most typical high-current linear regulators, the LM1117-Q1 consumes significantly less quiescent current. This device delivers excellent line and load transient performance. The device is low noise and exhibits a very good PSRR. As a result, the LM1117-Q1 is designed for high-current automotive applications that require very sensitive power-supply rails.

This regulator offers both current limit and thermal protection. The operating ambient temperature range of the device is –40°C to +125°C.

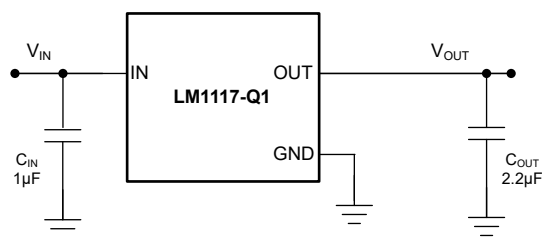Figure 7-2 shows a typical application circuit for this device.

Figure 7-2. Typical Application Circuit

7.2.1 Design Requirements

For this design example, use the parameters listed in Table 7-1 as the input parameters.

Table 7-1. Design Parameters

| PARAMETER	DESIGN REQUIREMENT
Input voltage	12V
Output voltage	3.3V
Output current	100mA

7.2.2 Detailed Design Procedure

For this design example, the 3.3V, fixed-version LM111733QxxxRQ1 is selected and is powered by a standard 12V input supply. The dropout voltage (V_{DO}) is kept within the LM1117-Q1 dropout voltage specification for the 3.3V output voltage option to keep the device in regulation under all load and temperature conditions for this design. A 1.0µF output capacitor is recommended for excellent load transient response. The input capacitor is optional and is used to reduce the input impedance of the circuit and improve the transient response.

As with any regulator, increasing the size of the output capacitor reduces overshoot and undershoot magnitude.
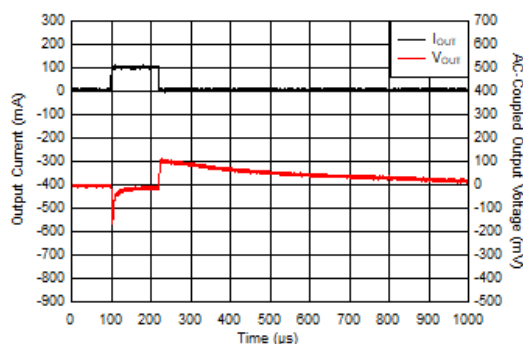
7.2.3 Application Curves

at operating temperature T_J = 25°C, V_{IN} = $V_{OUT(NOM)}$ + 1.5V or 2.5V (whichever is greater), I_{OUT} = 10mA, C_{IN} = 1.0µF, and C_{OUT} = 1.0µF (unless otherwise noted).
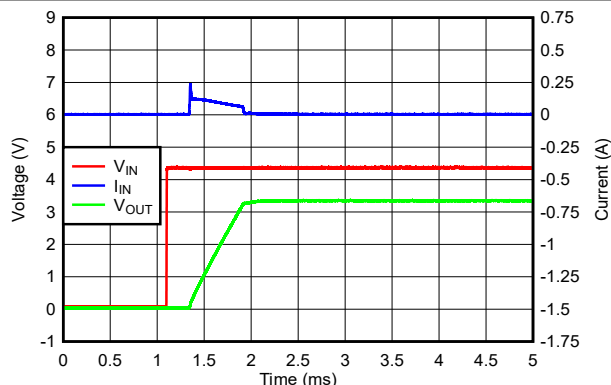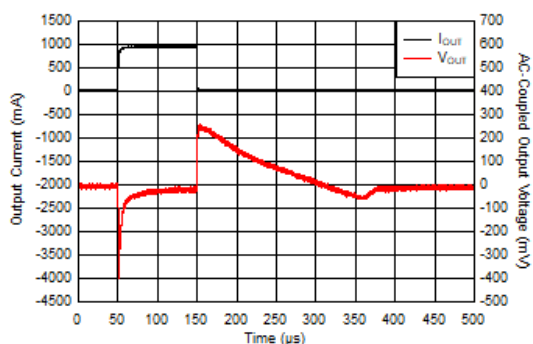

I_{OUT} = 0.1A, C_{OUT} = 22µF

Figure 7-3. Start-up and Inrush Current With 22µF at C_{OUT}

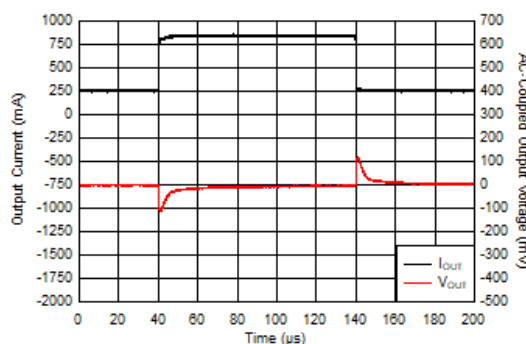V_{IN} = 5V, V_{OUT} = 3.3V, ramp rate = 0.4A/µs

Figure 7-4. I_{OUT} Transient From 0mA to 100mA

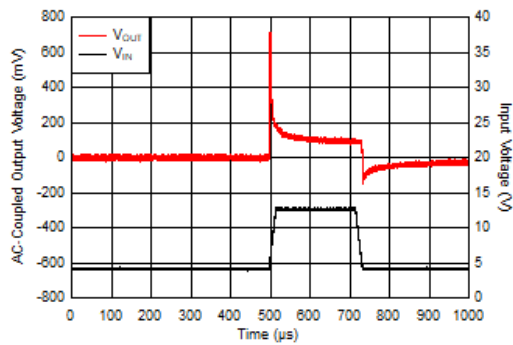V_{IN} = 5V, V_{OUT} = 3.3V, ramp rate = 0.5A/µs
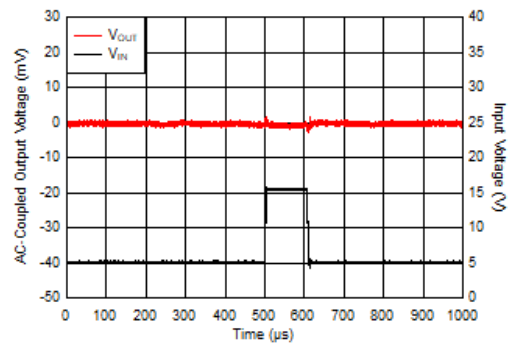
Figure 7-5. I_{OUT} Transient From 1mA to 1A

V_{IN} = 5V, V_{OUT} = 3.3V, ramp rate = 0.8A/µs

Figure 7-6. I_{OUT} Transient From 250mA to 850mA

V_{IN} = 5V, V_{OUT} = 3.3V, I_{OUT} = 1A, V_{IN} ramp rate = 0.6V/µs

Figure 7-7. V_{IN} Transient in Dropout From 4V to 13V

V_{OUT} = 3.3V, I_{OUT} = 33µA, V_{IN} ramp rate = 1.6V/µs

Figure 7-8. V_{IN} Transient From 5V to 16V

7.3 Best Design Practices

Place input and output capacitors as close to the device as possible.

Use a ceramic output capacitor.

Do not exceed the device absolute maximum ratings.

7.4 Power Supply Recommendations

Connect a low output impedance power supply directly to the input pin of the device. Inductive impedances between the input supply and the input pin creates significant voltage excursions at the input pin during start-up or load transient events.

Product Folder Links: *LM1117-Q1*

7.5 Layout

7.5.1 Layout Guidelines

Place input and output capacitors as close to the device pins as possible. To improve characteristic AC performance such as PSRR, output noise, and transient response, design the board with separate ground planes for V_{IN} and V_{OUT}, with the ground plane connected only at the GND pin of the device. In addition, connect the ground connection for the output capacitor directly to the device GND pin. Higher value ESR capacitors degrade PSRR performance.
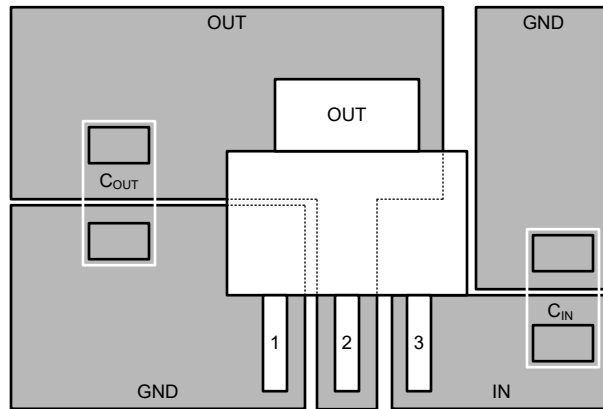
7.5.2 Layout Examples
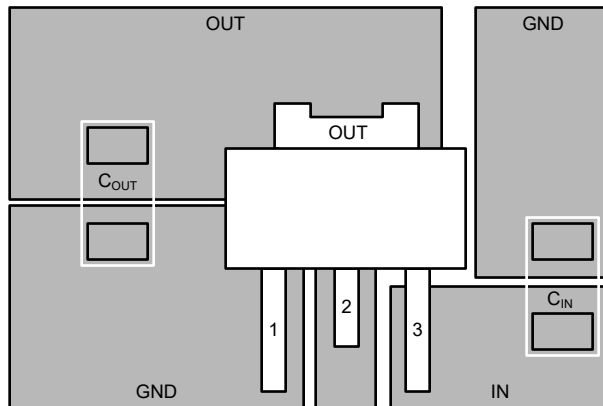

Figure 7-9. Layout Example for DCY (SOT-223) Package

Figure 7-10. Layout Example for KVU (TO-252) Package

Product Folder Links: *LM1117-Q1*

8 Device and Documentation Support

8.1 Device Support

8.1.1 Device Nomenclature

Table 8-1. Available Options

PRODUCT[1] [2]	DESCRIPTION
LM1117 *xx*Q*yyyz* **Q1**	**xx** is the nominal output voltage. For example: 12 for 1.2V, 33 for 3.3V, 50 for 5.0V, and 12V0 for 12.0V. **Q** indicates that this device is a grade-1 device in accordance with the AEC-Q100 standard. **yyy** is the package designator. For example: DCY for SOT-223, KVU for TO-252. **z** is the package quantity. R is for reel. **Q1** indicates that this device is an automotive grade (AEC-Q100) device.

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or visit the device product folder at www.ti.com.

(2) The device is available in factory-programmable fixed output voltage increments of 100mV upon request.

8.2 Documentation Support

8.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, *TLV767-Q1 Automotive Adjustable- and Fixed-Output 1A Linear Voltage Regulator* data sheet
- Texas Instruments, *TLV766-Q1 Automotive Adjustable- and Fixed-Output 500mA Linear Voltage Regulator* data sheet
- Texas Instruments, *LM1117 800mA Low-Dropout Linear Regulator* data sheet
- Texas Instruments, *Know Your Limits* application note
- Texas Instruments, *An empirical analysis of the impact of board layout on LDO thermal performance* application note

8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.4 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

8.6 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.7 Glossary

TI Glossary   This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision * (December 2024) to Revision A (June 2025)   **Page**

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
PLM1117120QDCYRQ1	Active	Preproduction	SOT-223 (DCY) | 4	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
PLM1117120QDCYRQ1.A	Active	Preproduction	SOT-223 (DCY) | 4	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
PLM1117120QKVURQ1	Active	Preproduction	TO-252 (KVU) | 3	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
PLM1117120QKVURQ1.A	Active	Preproduction	TO-252 (KVU) | 3	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
PLM111733QDCYRQ1	Active	Preproduction	SOT-223 (DCY) | 4	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
PLM111733QDCYRQ1.A	Active	Preproduction	SOT-223 (DCY) | 4	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
PLM111733QKVURQ1	Active	Preproduction	TO-252 (KVU) | 3	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
PLM111733QKVURQ1.A	Active	Preproduction	TO-252 (KVU) | 3	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
PLM111750QDCYRQ1	Active	Preproduction	SOT-223 (DCY) | 4	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
PLM111750QDCYRQ1.A	Active	Preproduction	SOT-223 (DCY) | 4	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
PLM111750QKVURQ1	Active	Preproduction	TO-252 (KVU) | 3	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	
PLM111750QKVURQ1.A	Active	Preproduction	TO-252 (KVU) | 3	2500 | LARGE T&R	-	Call TI	Call TI	-40 to 125	

(1) Status: For more details on status, see our product life cycle.

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF LM1117-Q1 :

● Catalog : LM1117

NOTE: Qualified Version Definitions:

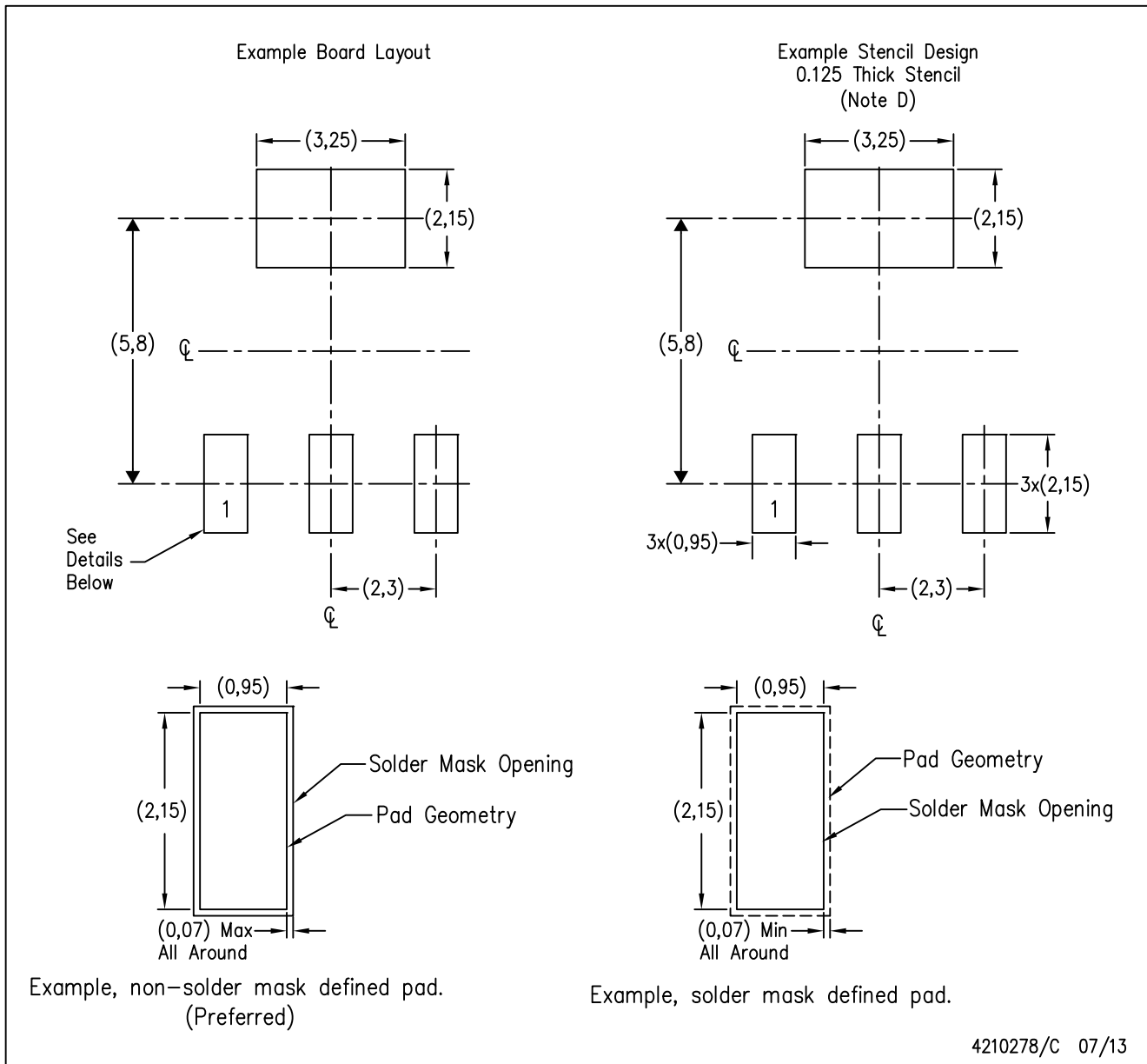● Catalog - TI's standard catalog product

**DCY (R-PDSO-G4)**   **PLASTIC SMALL-OUTLINE**

6,70 (0.264)
6,30 (0.248)

3,10 (0.122)
2,90 (0.114)

⊕ 0,10 (0.004) Ⓜ

4

7,30 (0.287)
6,70 (0.264)

3,70 (0.146)
3,30 (0.130)

Gauge Plane

0°–10°

0,25 (0.010)

1   2   3

2,30 (0.091)

0,84 (0.033)
0,66 (0.026)

⊕ 0,10 (0.004) Ⓜ

4,60 (0.181)

0,75 (0.030) MIN

1,70 (0.067)
1,50 (0.059)

1,80 (0.071) MAX

0,35 (0.014)
0,23 (0.009)

Seating Plane

0,10 (0.0040)
0,02 (0.0008)

◠ 0,08 (0.003)

4202506/B 06/2002

NOTES: A. All linear dimensions are in millimeters (inches).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion.
D. Falls within JEDEC TO-261 Variation AA.

**TEXAS
INSTRUMENTS**

POST OFFICE BOX 655303 ● DALLAS, TEXAS 75265

DCY (R−PDSO−G4)   PLASTIC SMALL OUTLINE

Example Board Layout

Example Stencil Design
0.125 Thick Stencil
(Note D)

(3,25)

(2,15)

(5,8)

1

See
Details
Below

(2,3)

(3,25)

(2,15)

(5,8)

3x(2,15)

3x(0,95)

1

(2,3)

(0,95)

Solder Mask Opening

Pad Geometry

(2,15)

(0,07) Max
All Around

Example, non−solder mask defined pad.
(Preferred)

(0,95)

Pad Geometry

Solder Mask Opening

(2,15)

(0,07) Min
All Around

Example, solder mask defined pad.

4210278/C 07/13

NOTES: A.   All linear dimensions are in millimeters.
         B.   This drawing is subject to change without notice.
         C.   Publication IPC−7351 is recommended for alternate designs.
         D.   Laser cutting apertures with trapezoidal walls and also rounding corners will
              offer better paste release. Customers should contact their board assembly
              site for stencil recommendations. Refer to IPC 7525 for stencil design
              considerations.
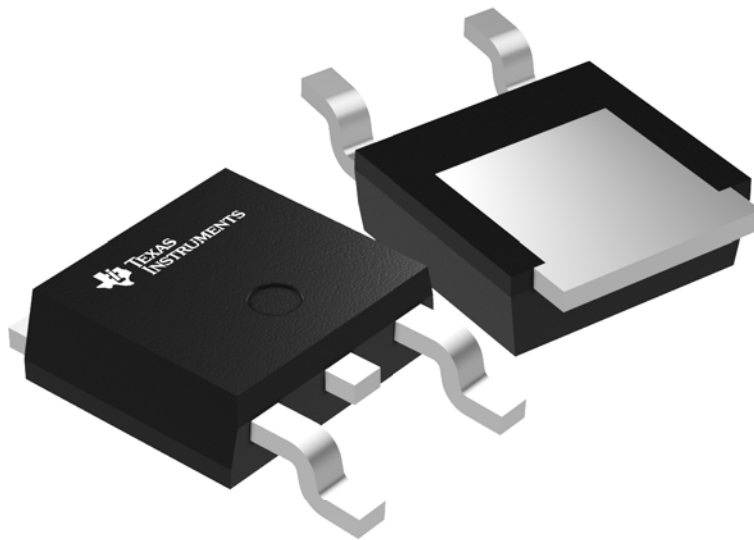
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4205521-2/E
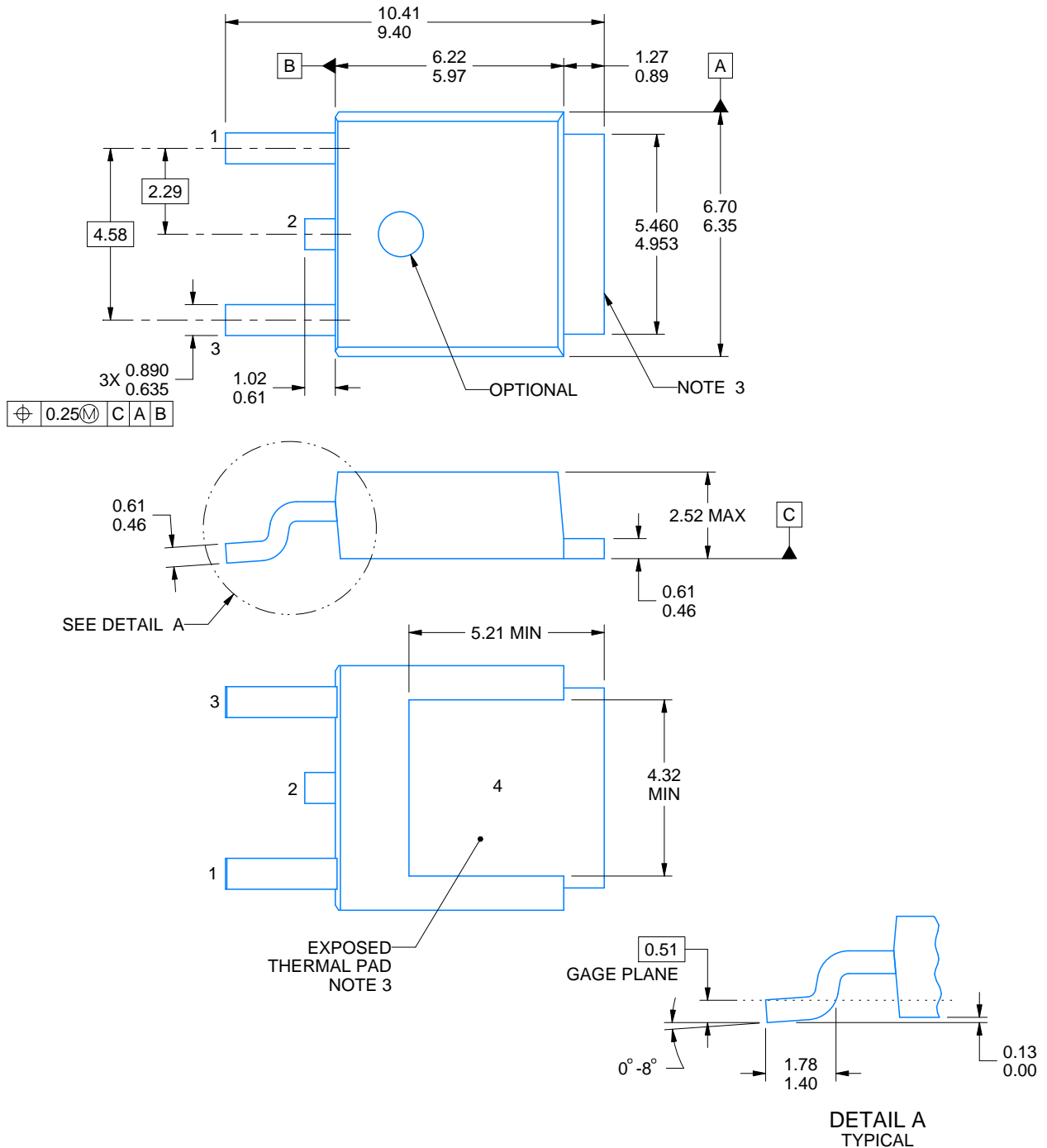
4218915/A 02/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Shape may vary per different assembly sites.
4. Reference JEDEC registration TO-252.

TEXAS INSTRUMENTS
www.ti.com
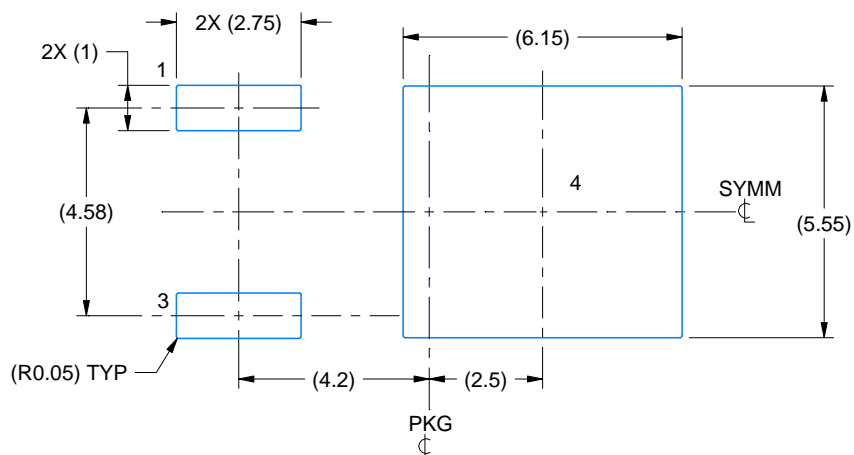
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:6X

2X (2.75)

2X (1)

1

(4.58)

(6.15)

4

SYMM

(5.55)

3

(R0.05) TYP

(4.2)

(2.5)

PKG

0.07 MAX
ALL AROUND

EXPOSED
METAL

SOLDER MASK
OPENING

METAL

NON SOLDER MASK
DEFINED

0.07 MIN
ALL AROUND

EXPOSED
METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

SOLDER MASK
DEFINED
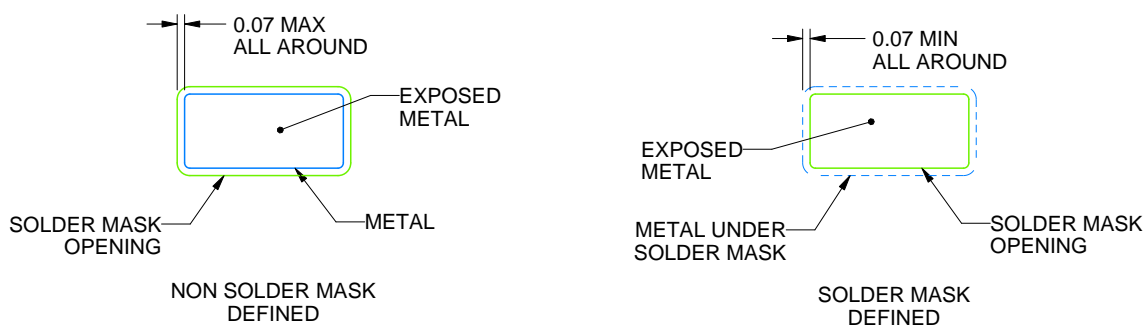
SOLDER MASK DETAILS
NOT TO SCALE

4218915/A   02/2017

NOTES: (continued)

5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers
   SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).
6. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

(1.18) TYP

2X (2.75)

2X (1)

1

(0.14)

(R0.05)

(1.33) TYP

(4.58)

SYMM

4

3

20X (1.13)

(4.2)

20X (0.98)

PKG
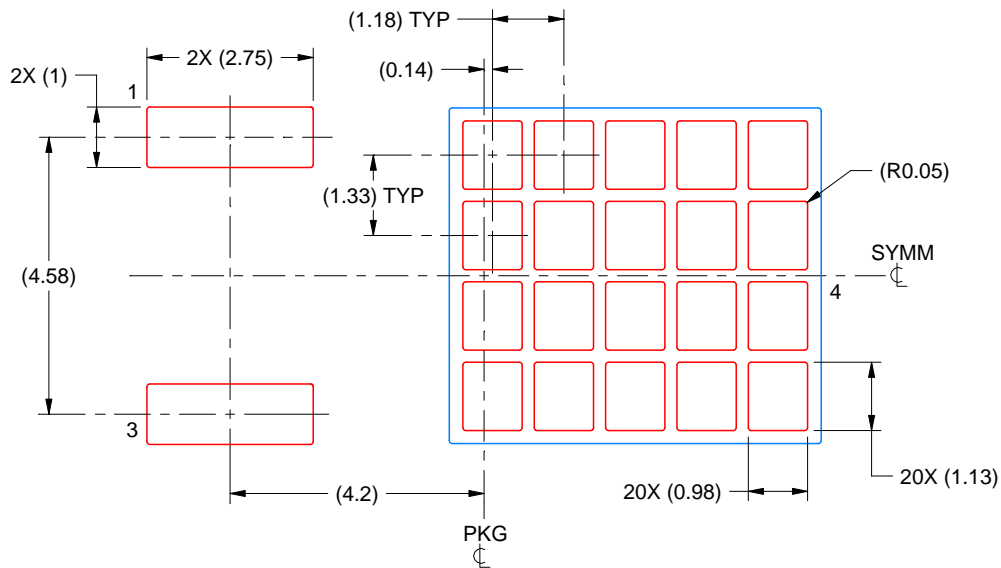
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
65% PRINTED SOLDER COVERAGE BY AREA
SCALE:8X

4218915/A   02/2017

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
design recommendations.
8. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER